

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type(U-MOSIX-H)

SSM6K513NU

Power Management Switch Applications

- 4.5V drive
- Low ON-resistance: $R_{DS(ON)} = 8.0\text{ m}\Omega$ (typ.) (@ $V_{GS} = 4.5\text{V}$)
 $R_{DS(ON)} = 6.5\text{ m}\Omega$ (typ.) (@ $V_{GS} = 10\text{V}$)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-Source voltage	V_{DSS}	30	V
Gate-Source voltage	V_{GSS}	± 20	V
Drain current	DC	I_D	15
	Pulse	I_{DP} (Note 2)	50
Power dissipation	P_D (Note 3)	1.25	W
	$t \leq 10\text{s}$	2.5	
Single-pulse avalanche energy	E_{AS} (Note 4)	17.9	mJ
Avalanche current	I_{AR}	15	A
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

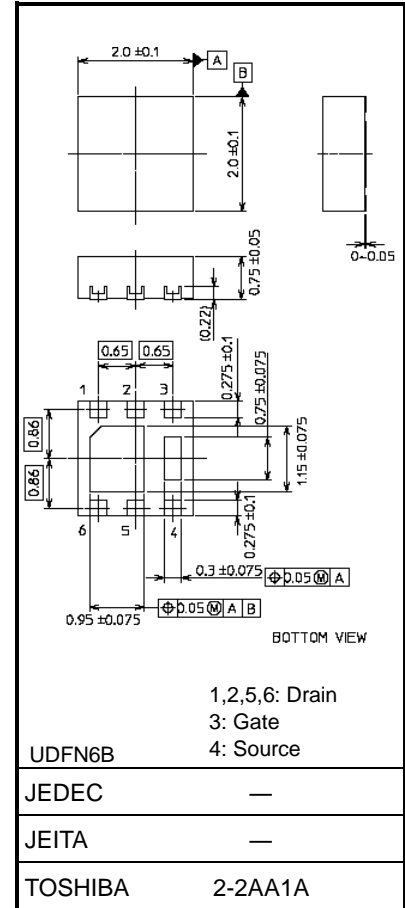
Note 2: $PW \leq 10\mu\text{s}$, $Duty \leq 1\%$

Note 3: Mounted on a FR4 board.

(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm²)

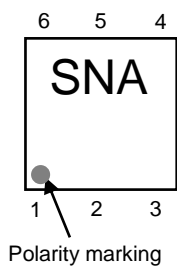
Note 4: $V_{DD} = 24\text{V}$, $T_{ch} = 25^\circ\text{C}$ (Initial state), $L = 50\mu\text{H}$, $R_G = 25\Omega$,

Unit: mm

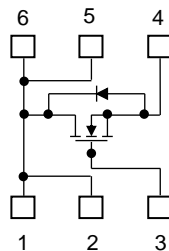


Weight: 8.5 mg (typ.)

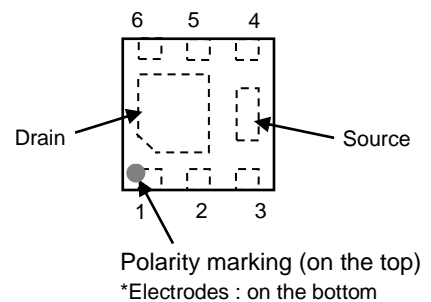
Marking(Top View)



Equivalent Circuit(Top View)



Pin Condition(Top View)



Electrical Characteristics (Ta = 25°C)

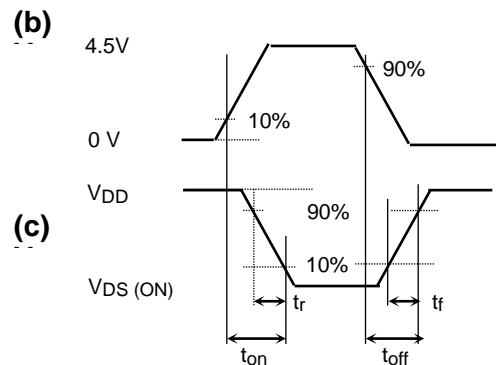
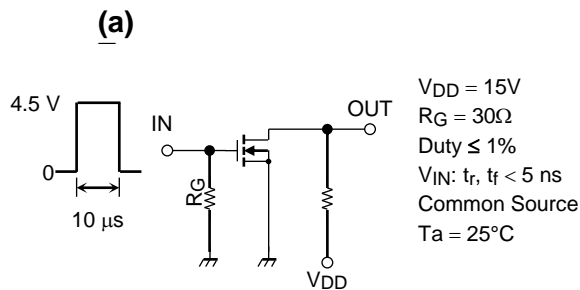
Characteristic	Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-Source breakdown voltage	V (BR) DSS	ID = 10 mA, VGS = 0 V	30	—	—	V
	V (BR) DSX	ID = 10 mA, VGS = -20 V (Note 5)	27	—	—	
Drain cut-off current	IDSS	VDS = 30 V, VGS = 0 V	—	—	1	μA
Gate leakage current	IGSS	VGS = ±20 V, VDS = 0 V	—	—	±100	nA
Gate threshold voltage	Vth	VDS = 10 V, ID = 0.1 mA	1.1	—	2.1	V
Forward transfer admittance	Yfs	VDS = 10 V, ID = 2.0 A (Note 6)	—	6.8	—	S
Drain-source ON-resistance	RDS (ON)	ID = 4 A, VGS = 10 V (Note 6)	—	6.5	8.9	mΩ
		ID = 4 A, VGS = 4.5 V (Note 6)	—	8.0	12	
Input capacitance	Ciss	VDS = 15 V, VGS = 0 V, f = 1 MHz	—	1130	—	pF
Output capacitance	Coss		—	350	—	
Reverse transfer capacitance	Crss		—	52	—	
Total Gate Charge	Qg	VDD = 15 V, ID = 15 A VGS = 4.5 V	—	7.5	—	nC
Gate-Source Charge1	Qgs1		—	3.0	—	
Gate-Drain Charge	Qgd		—	2.2	—	
Switching time	Turn-on time	t _{on}	VDD = 15 V, ID = 1.0 A, VGS = 0 to 4.5 V, RG = 30 Ω	—	28	ns
	Turn-off time	t _{off}		—	33	
Drain-Source forward voltage	VDSF	ID = -4.0 A, VGS = 0 V (Note 3)	—	-0.76	-1.2	V

Note 5: If a reverse bias is applied between gate and source, this device enters V(BR)DSX mode.

Note that the drain-source breakdown voltage is lowered in this mode

Note 6: Pulse test

Switching Time Test Circuit



Precaution

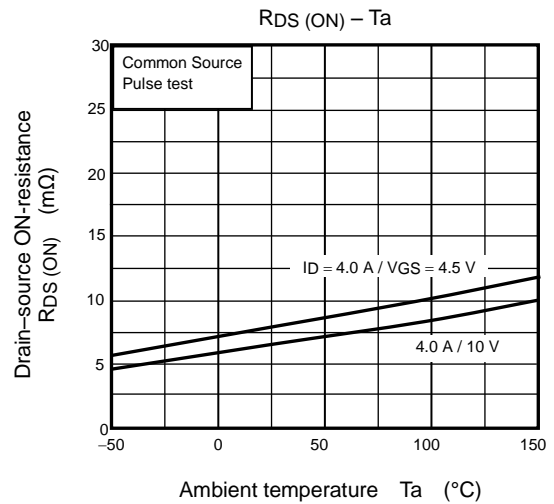
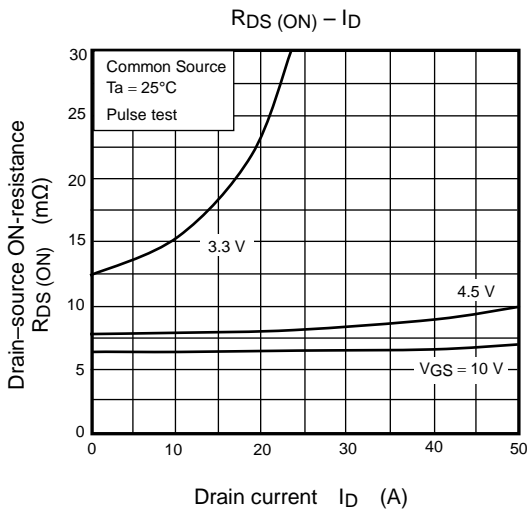
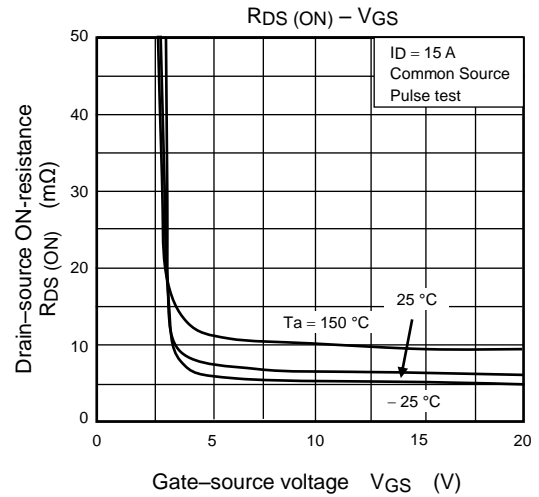
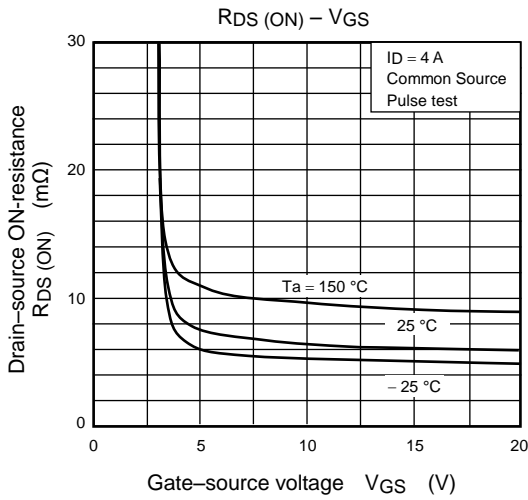
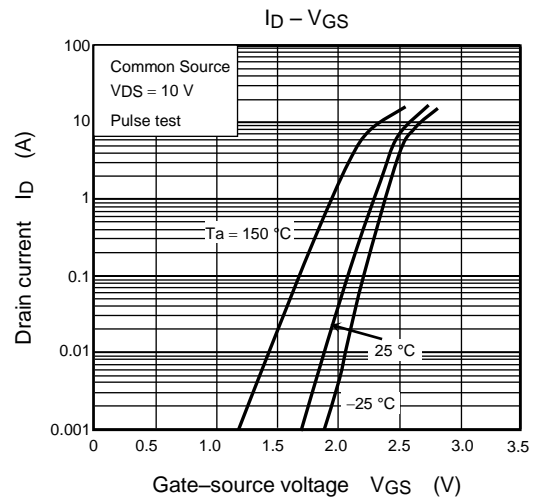
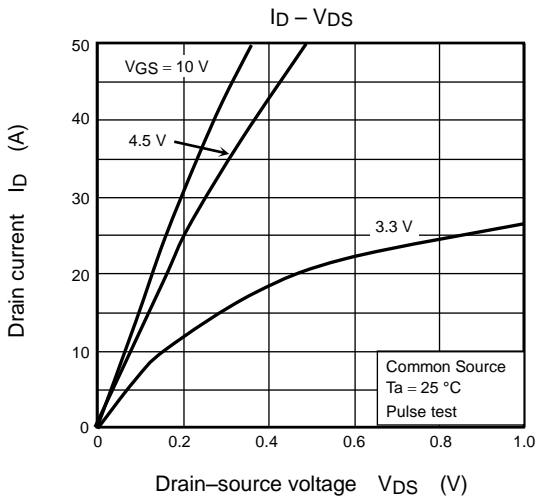
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to be low (0.1 mA for the SSM6K513NU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

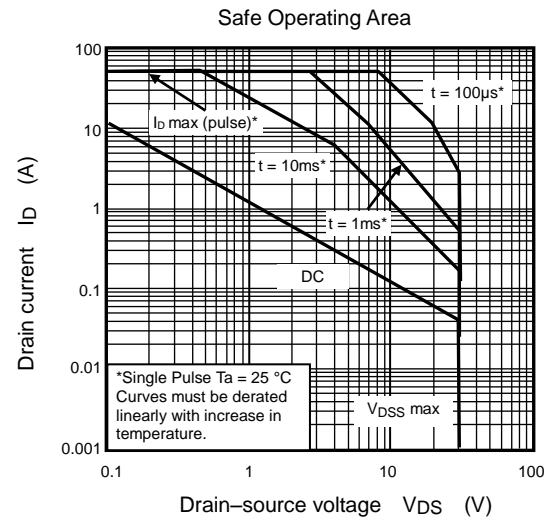
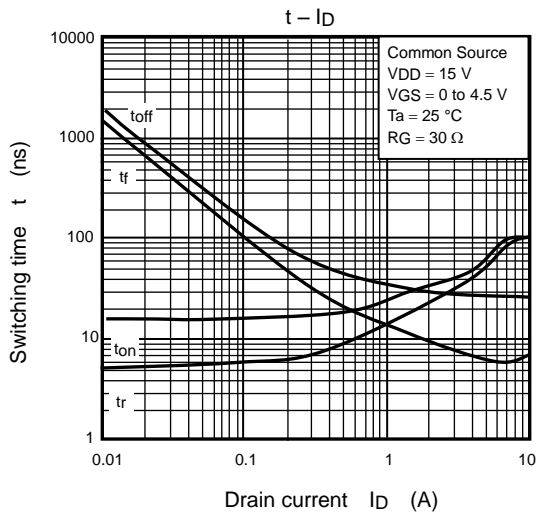
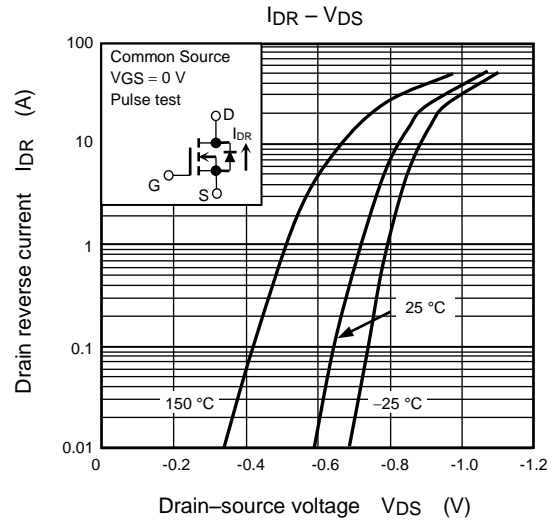
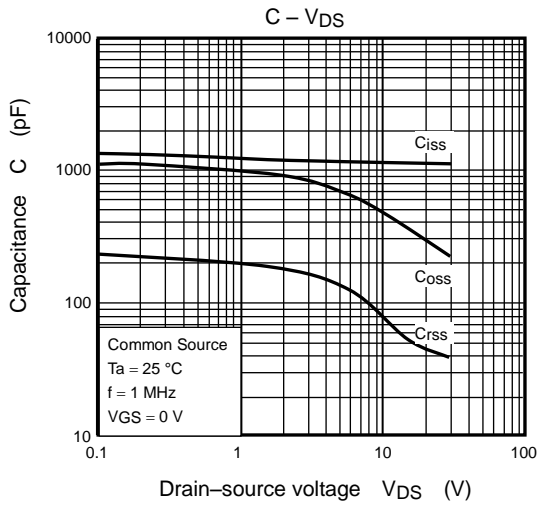
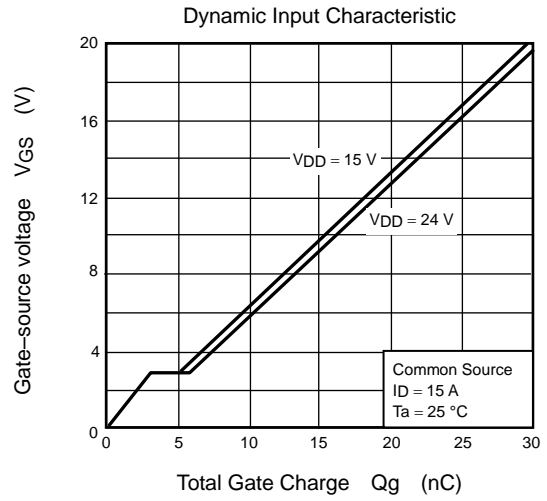
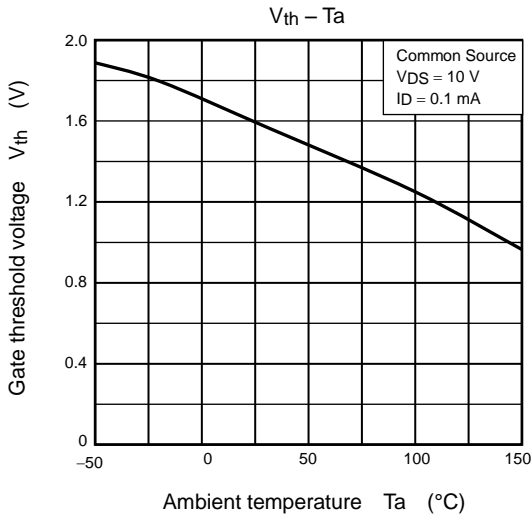
Take this into consideration when using the device.

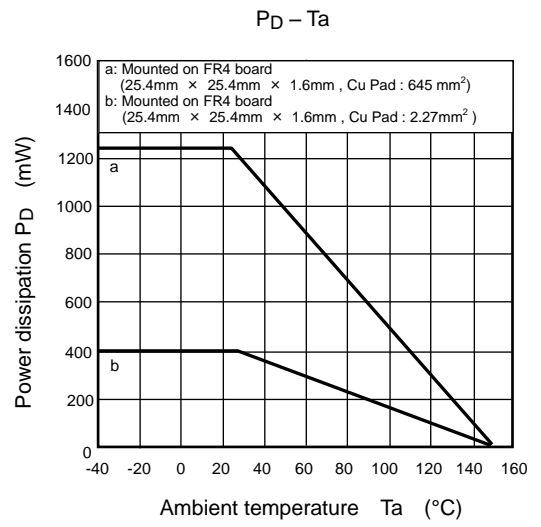
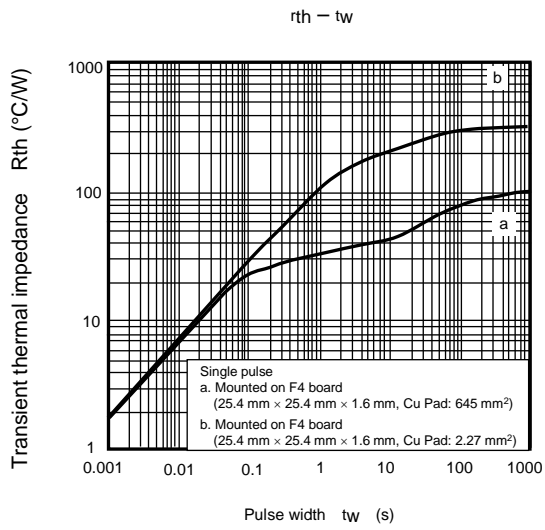
Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

Thermal resistance R_{th} (ch-a) and power dissipation PD vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration







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